

Rectifier diodes ultrafast

BYV79 series

GENERAL DESCRIPTION

Glass passivated high efficiency rectifier diodes in a plastic envelope, featuring low forward voltage drop, ultra-fast recovery times and soft recovery characteristic. They are intended for use in switched mode power supplies and high frequency circuits in general where low conduction and switching losses are essential.

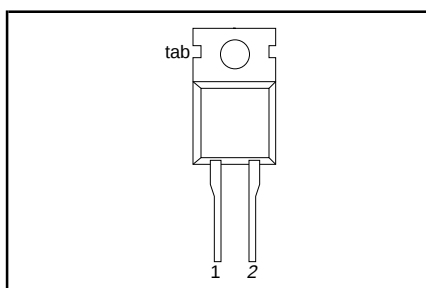
QUICK REFERENCE DATA

SYMBOL	PARAMETER	MAX.	MAX.	MAX.	UNIT
V_{RRM}	BYV79- Repetitive peak reverse voltage	100 100	150 150	200 200	V
V_F	Forward voltage	0.9	0.9	0.9	V
$I_{F(AV)}$	Forward current	14	14	14	A
t_{rr}	Reverse recovery time	30	30	30	ns

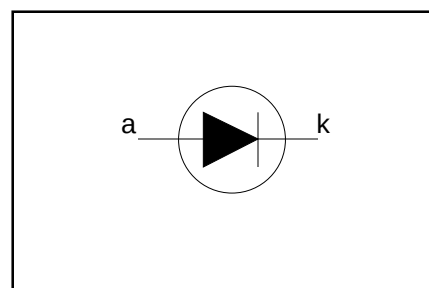
PINNING - TO220AC

PIN	DESCRIPTION
1	cathode (k)
2	anode (a)
tab	cathode (k)

PIN CONFIGURATION



SYMBOL



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.			UNIT
V_{RRM}	Repetitive peak reverse voltage	square wave; $\delta = 0.5$; $T_{mb} \leq 120^\circ\text{C}$ sinusoidal; $a = 1.57$; $T_{mb} \leq 122^\circ\text{C}$	-	-100 100	-150 150	-200 200	V
V_{RWM}	Crest working reverse voltage		-	100	150	200	V
V_R	Continuous reverse voltage ¹		-	100	150	200	V
$I_{F(AV)}$	Average forward current ²	$t = 25\ \mu\text{s}$; $\delta = 0.5$; $T_{mb} \leq 120^\circ\text{C}$	-	14			A
$I_{F(RMS)}$	RMS forward current		-	12.7			A
I_{FRM}	Repetitive peak forward current		-	20			A
I_{FSM}	Non-repetitive peak forward current	$t = 10\ \text{ms}$	-	28			A
		$t = 8.3\ \text{ms}$	-	150			A
		sinusoidal; with reapplied	-	160			A
I^2t	I^2t for fusing	$V_{RWM(max)}$ $t = 10\ \text{ms}$	-	112			A ² s
T_{stg}	Storage temperature		-40	150			$^\circ\text{C}$
T_j	Operating junction temperature		-	150			$^\circ\text{C}$

1 $T_{mb} \leq 145^\circ\text{C}$ for thermal stability.

2 Neglecting switching and reverse current losses.

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THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$R_{th\ j-mb}$	Thermal resistance junction to mounting base	in free air	-	-	2.0	K/W
$R_{th\ j-a}$	Thermal resistance junction to ambient		-	60	-	K/W

STATIC CHARACTERISTICS

$T_j = 25\ ^\circ\text{C}$ unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V_F	Forward voltage	$I_F = 14\ \text{A}; T_j = 150\ ^\circ\text{C}$	-	0.83	0.90	V
		$I_F = 14\ \text{A}$	-	0.95	1.05	V
		$I_F = 50\ \text{A}$	-	1.20	1.30	V
I_R	Reverse current	$V_R = V_{RWM}; T_j = 100\ ^\circ\text{C}$	-	0.5	1.3	mA
		$V_R = V_{RWM}$	-	5	50	μA

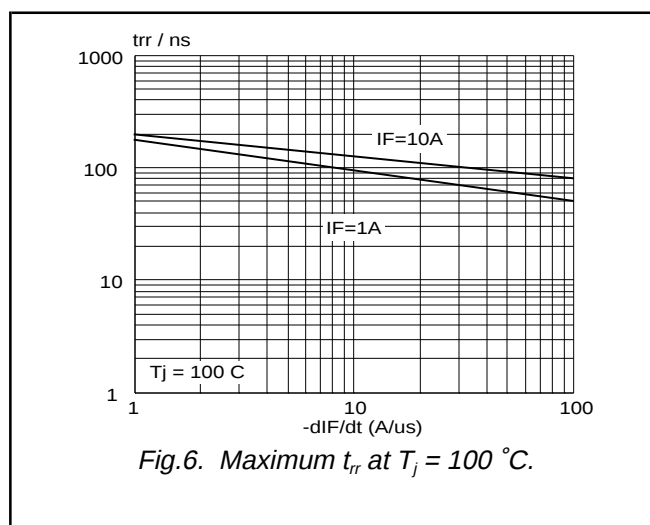
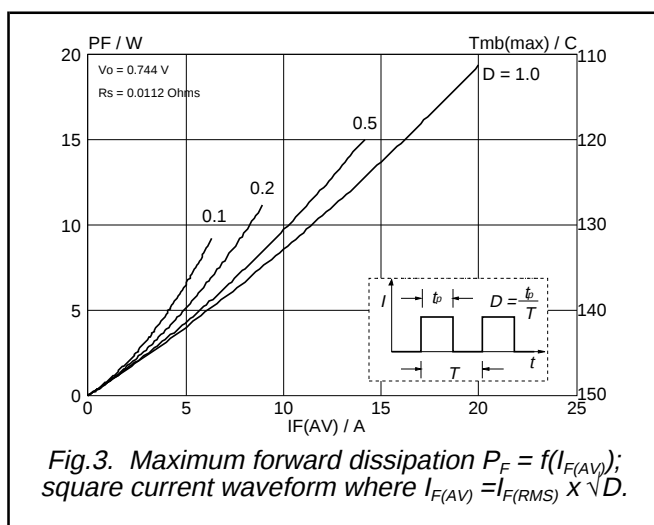
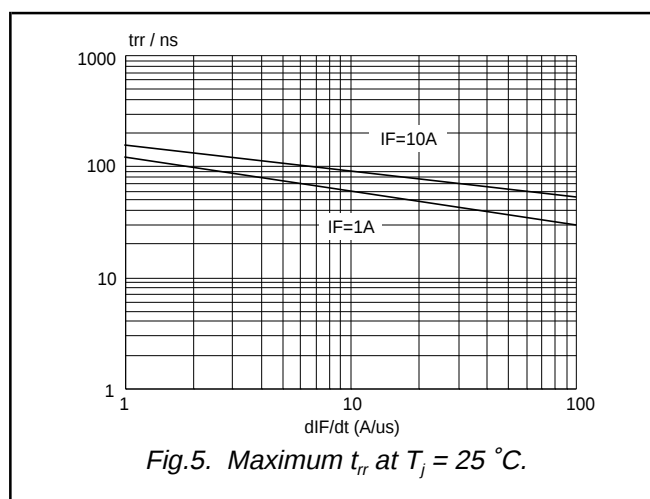
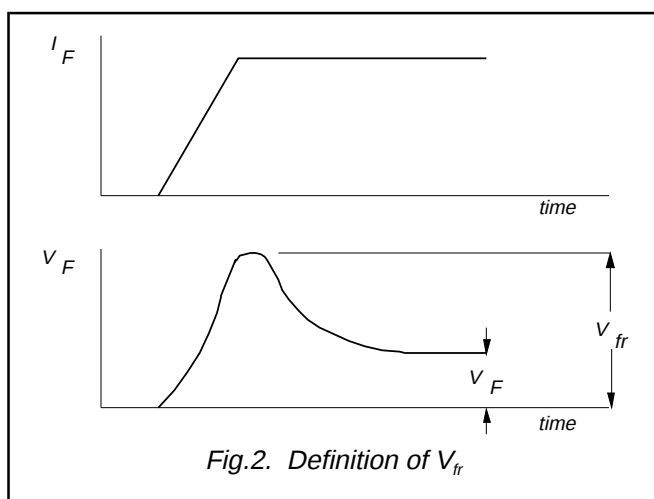
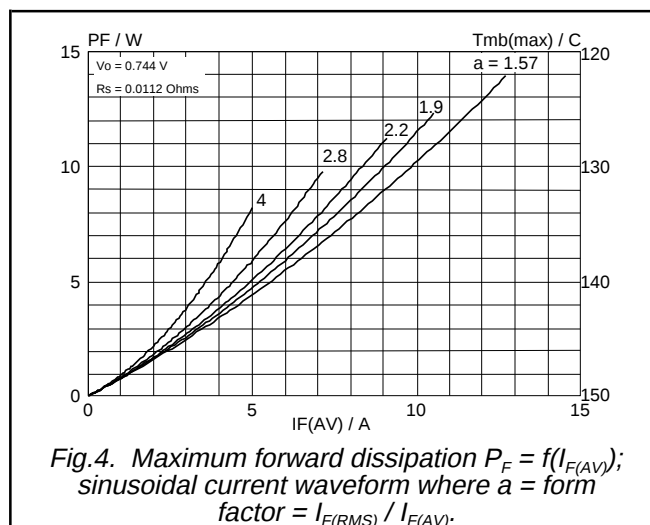
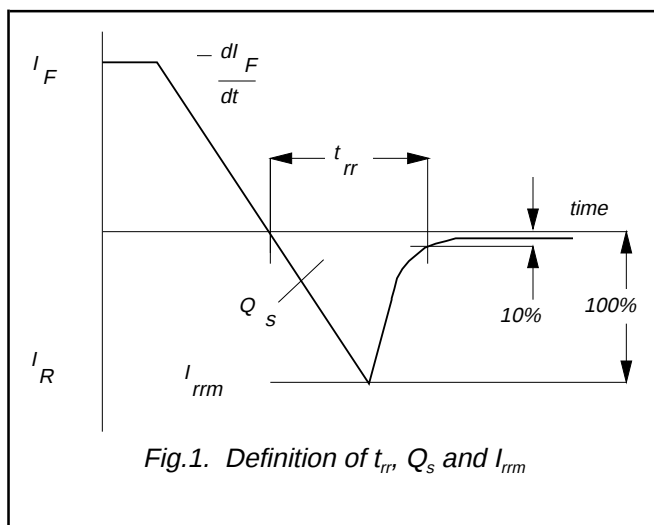
DYNAMIC CHARACTERISTICS

$T_j = 25\ ^\circ\text{C}$ unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Q_s	Reverse recovery charge	$I_F = 2\ \text{A}; V_R \geq 30\ \text{V}; -di_F/dt = 20\ \text{A}/\mu\text{s}$	-	6	15	nC
t_{rr}	Reverse recovery time	$I_F = 1\ \text{A}; V_R \geq 30\ \text{V}; -di_F/dt = 100\ \text{A}/\mu\text{s}$	-	20	30	ns
I_{rrm}	Peak reverse recovery current	$I_F = 10\ \text{A}; V_R \geq 30\ \text{V}; -di_F/dt = 50\ \text{A}/\mu\text{s}; T_j = 100\ ^\circ\text{C}$	-	3	4	A
V_{fr}	Forward recovery voltage	$I_F = 10\ \text{A}; di_F/dt = 10\ \text{A}/\mu\text{s}$	-	1	-	V

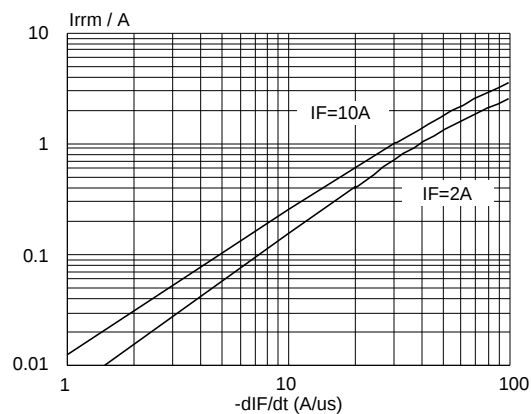
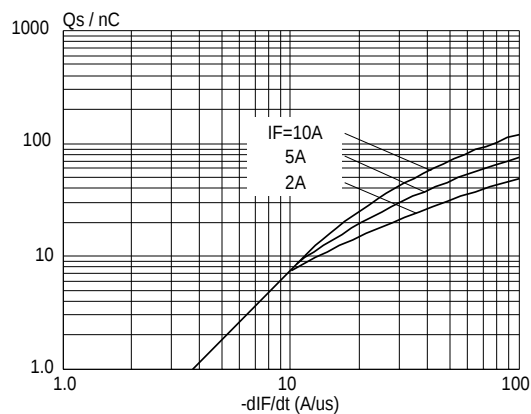
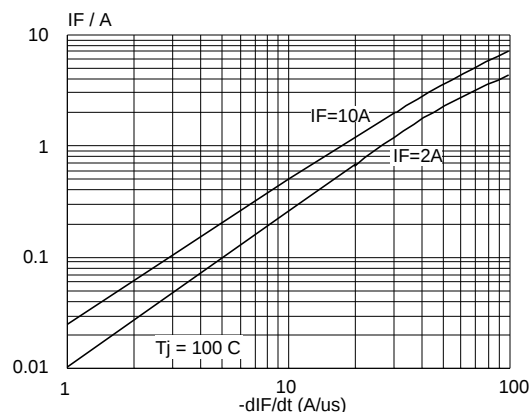
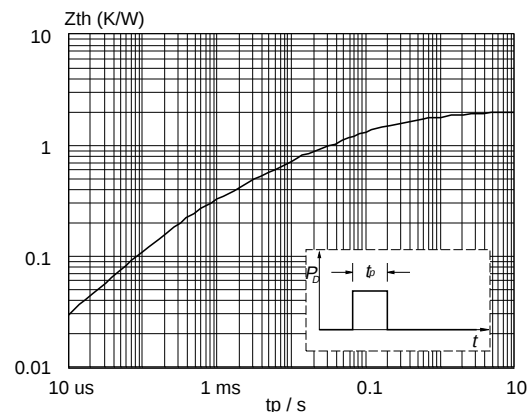
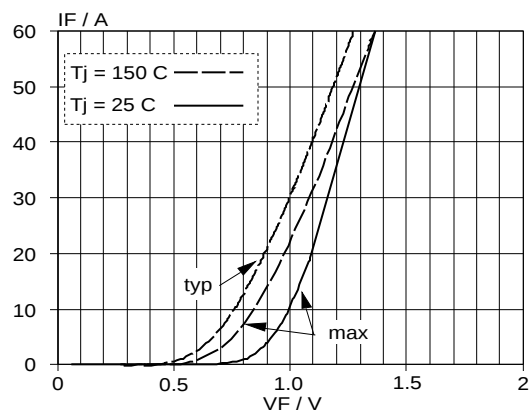
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Fig. 7. Maximum I_{rms} at $T_j = 25^\circ\text{C}$.Fig. 10. Maximum Q_s at $T_j = 25^\circ\text{C}$.Fig. 8. Maximum I_{rms} at $T_j = 100^\circ\text{C}$.Fig. 11. Transient thermal impedance; $Z_{th\ j-mb} = f(t_p)$.Fig. 9. Typical and maximum forward characteristic $I_F = f(V_F)$; parameter T_j

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MECHANICAL DATA

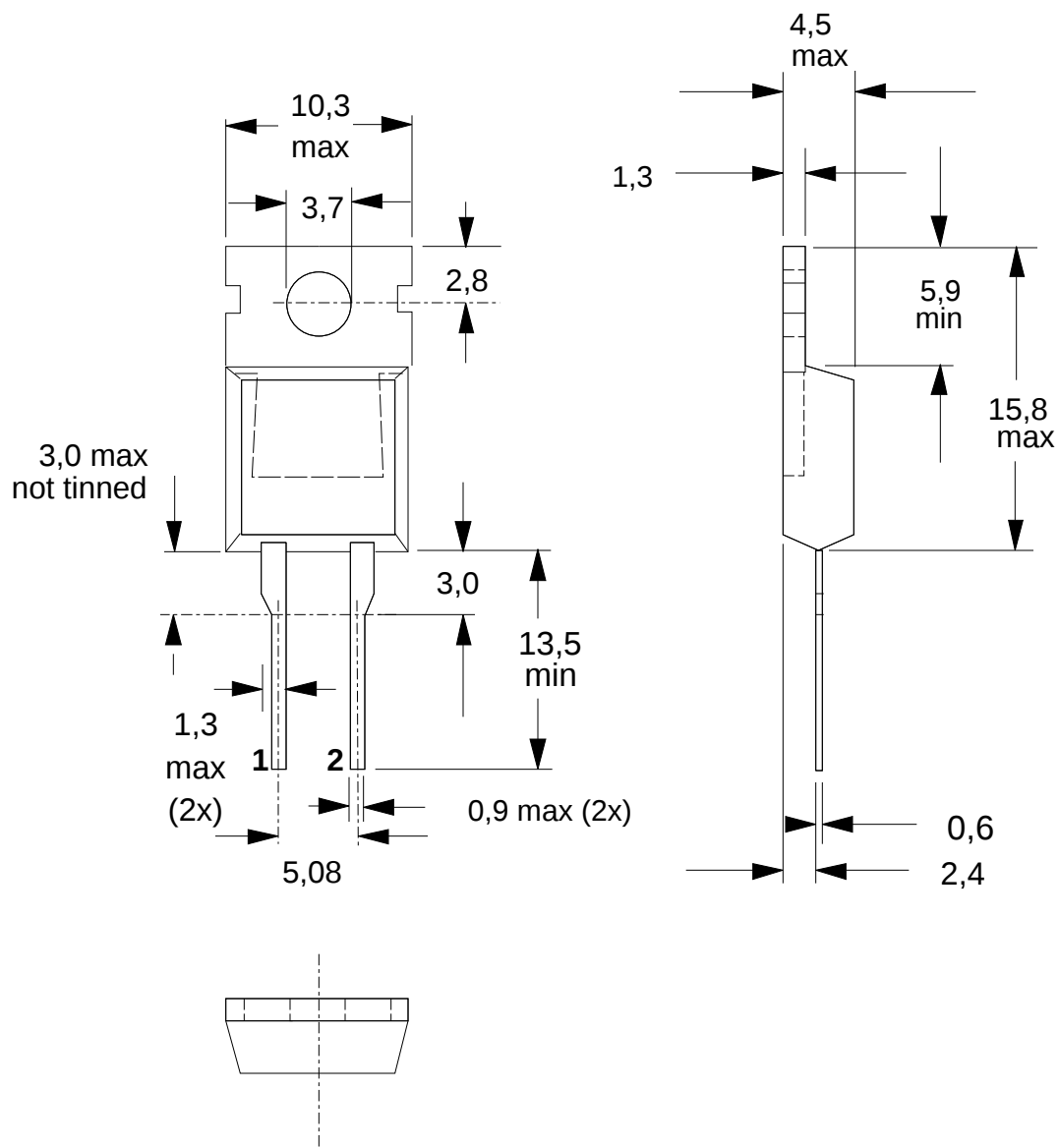
*Dimensions in mm**Net Mass: 2 g*

Fig.12. TO220AC; pin 1 connected to mounting base.

Notes

1. Accessories supplied on request: refer to mounting instructions for TO220 envelopes.
2. Epoxy meets UL94 V0 at 1/8".

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DEFINITIONS

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
Application information	
Where application information is given, it is advisory and does not form part of the specification.	
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